

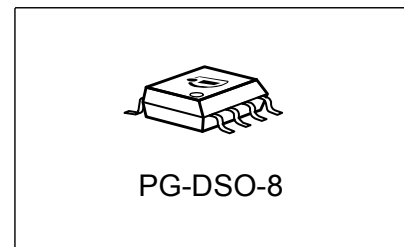
Smart Power High-Side-Switch for Industrial Applications

Features

- Overload protection
- Current limitation
- Short circuit protection
- Thermal shutdown with restart
- ESD - Protection
- Overvoltage protection (including load dump)
- Fast demagnetization of inductive loads
- Reverse battery protection with external resistor
- Open drain diagnostic output for overtemperature and short circuit
- Open load detection in OFF - State with external resistor
- CMOS compatible input
- Loss of GND and loss of V_{bb} protection
- Very low standby current

Product Summary

Overvoltage protection	$V_{bb(AZ)}$	62	V
Operating voltage	$V_{bb(on)}$	6 ... 52	V
On-state resistance	R_{ON}	200	m Ω
Nominal load current	$I_{L(nom)}$	1.3	A
Operating temperature	T_a	-30...+85	$^{\circ}\text{C}$



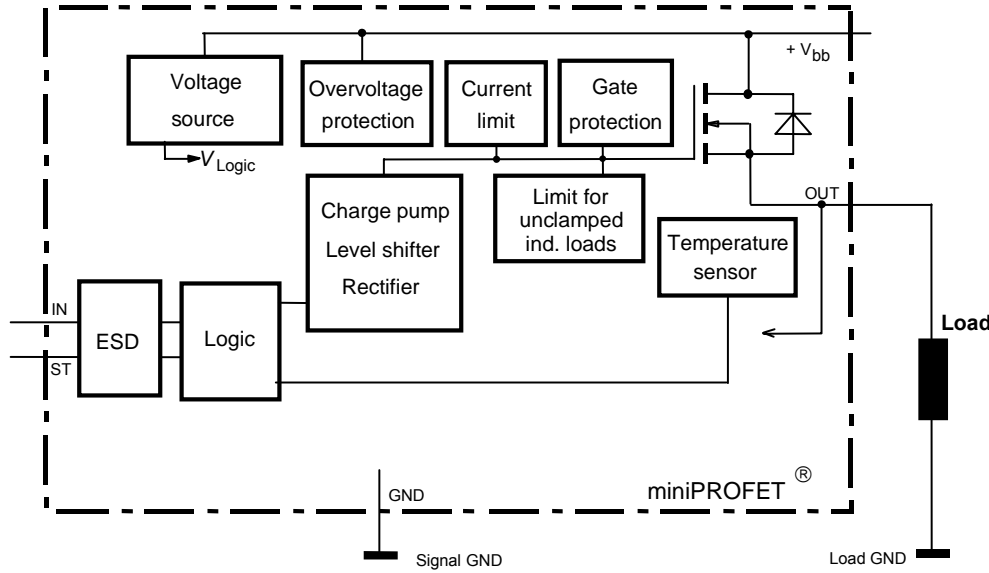
Application

- All types of resistive, inductive and capacitive loads
- μC compatible power switch for 12 V, 24 V and 42 V DC industrial applications
- Replaces electromechanical relays and discrete circuits

General Description

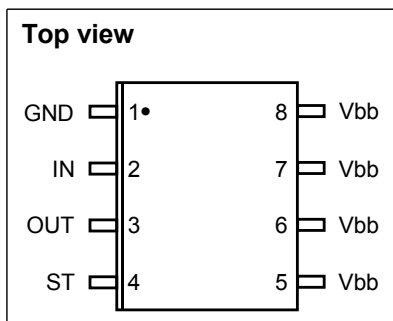
N channel vertical power FET with charge pump, ground referenced CMOS compatible input and diagnostic feedback, monolithically integrated in Smart SIPMOS[®] technology. Providing embedded protective functions.

Block Diagram



Pin	Symbol	Function
1	GND	Logic ground
2	IN	Input, activates the power switch in case of logic high signal
3	OUT	Output to the load
4	ST	Diagnostic feedback
5	Vbb	Positive power supply voltage
6	Vbb	Positive power supply voltage
7	Vbb	Positive power supply voltage
8	Vbb	Positive power supply voltage

Pin configuration



Maximum Ratings at $T_j = 25\text{ °C}$, unless otherwise specified

Parameter	Symbol	Value	Unit
Supply voltage	V_{bb}	52	V
Supply voltage for full short circuit protection	$V_{bb(SC)}$	50	
Continuous input voltage	V_{IN}	-10 ... +16	
Load current (Short - circuit current, see page 5)	I_L	self limited	A
Current through input pin (DC)	I_{IN}	± 5	mA
Junction temperature	T_j	150	$^{\circ}\text{C}$
Operating temperature	T_a	-30...+85	
Storage temperature	T_{stg}	-40 ... +105	
Power dissipation ¹⁾	P_{tot}	1.5	W
Inductive load switch-off energy dissipation ¹⁾²⁾ single pulse, (see page 9) $T_j = 150\text{ °C}$, $I_L = 1\text{ A}$	E_{AS}	125	mJ
Load dump protection ²⁾ $V_{LoadDump}^3) = V_A + V_S$ $R_I = 2\Omega$, $t_d = 400\text{ms}$, $V_{IN} = \text{low or high}$, $V_A = 13,5\text{V}$ $R_L = 13.5\ \Omega$ $R_L = 27\ \Omega$	$V_{Loaddump}$	73.5 83.5	V
Electrostatic discharge voltage (Human Body Model) according to ANSI EOS/ESD - S5.1 - 1993 ESD STM5.1 - 1998 Input pin all other pins	V_{ESD}	± 1 ± 5	kV

Thermal Characteristics

Thermal resistance @ min. footprint	$R_{th(JA)}$	-	95	-	K/W
Thermal resistance @ 6 cm ² cooling area ¹⁾	$R_{th(JA)}$	-	70	83	

¹⁾ Device on 50mm*50mm*1.5mm epoxy PCB FR4 with 6 cm² (one layer, 70µm thick) copper area for drain connection. PCB is vertical without blown air. (see page 17)

²⁾ not subject to production test, specified by design

³⁾ $V_{Loaddump}$ is setup without the DUT connected to the generator per ISO 7637-1 and DIN 40839 .

Supply voltages higher than $V_{bb(AZ)}$ require an external current limit for the GND pin, e.g. with a 150Ω resistor in GND connection. A resistor for the protection of the input is integrated.

Electrical Characteristics

Parameter and Conditions at $T_j = -40\dots+150^\circ\text{C}$, $V_{bb} = 12\dots42\text{V}$, unless otherwise specified	Symbol	Values			Unit
		min.	typ.	max.	

Load Switching Capabilities and Characteristics

On-state resistance $T_j = 25^\circ\text{C}$, $I_L = 1\text{A}$, $V_{bb} = 9\dots52\text{V}$ $T_j = 150^\circ\text{C}$	R_{ON}	-	150	200	m Ω
		-	270	380	
Nominal load current; Device on PCB ¹⁾ $T_C = 85^\circ\text{C}$, $T_j \leq 150^\circ\text{C}$	$I_{L(nom)}$	1.3	1.7	-	A
Turn-on time to 90% V_{OUT} $R_L = 47\ \Omega$	t_{on}	-	80	180	μs
Turn-off time to 10% V_{OUT} $R_L = 47\ \Omega$	t_{off}	-	80	200	
Slew rate on 10 to 30% V_{OUT} , $R_L = 47\ \Omega$, $V_{bb} = 13.5\text{V}$	dV/dt_{on}	-	0.7	2	V/ μs
Slew rate off 70 to 40% V_{OUT} , $R_L = 47\ \Omega$, $V_{bb} = 13.5\text{V}$	$-dV/dt_{off}$	-	0.9	2	

Operating Parameters

Operating voltage	$V_{bb(on)}$	6	-	52	V
Undervoltage shutdown of charge pump $T_j = -40\dots+85^\circ\text{C}$ $T_j = 150^\circ\text{C}$	$V_{bb(under)}$	-	-	4	
		-	-	5.5	
Undervoltage restart of charge pump	$V_{bb(u\ cp)}$	-	4	5.5	
Standby current $T_j = -40\dots+85^\circ\text{C}$, $V_{IN} = \text{low}$ $T_j = +150^\circ\text{C}^2)$, $V_{IN} = \text{low}$	$I_{bb(off)}$	-	-	15	μA
		-	-	18	
Leakage output current (included in $I_{bb(off)}$) $V_{IN} = \text{low}$	$I_{L(off)}$	-	-	5	
Operating current $V_{IN} = \text{high}$	I_{GND}	-	0.8	2	mA

¹Device on 50mm*50mm*1.5mm epoxy PCB FR4 with 6 cm² (one layer, 70 μm thick) copper area for drain connection. PCB is vertical without blown air. (see page 17)

²higher current due temperature sensor

Electrical Characteristics

Parameter and Conditions at $T_j = -40\dots+150^\circ\text{C}$, $V_{bb} = 12..42\text{V}$, unless otherwise specified	Symbol	Values			Unit
		min.	typ.	max.	
Protection Functions¹⁾					
Initial peak short circuit current limit (pin 5 to 3) $T_j = -40^\circ\text{C}$, $V_{bb} = 20\text{V}$, $t_m = 150\ \mu\text{s}$ $T_j = 25^\circ\text{C}$ $T_j = 150^\circ\text{C}$ $T_j = -40\dots+150^\circ\text{C}$, $V_{bb} > 40\text{V}$, (see page 12)	$I_{L(\text{SCP})}$	-	-	9	A
		-	6.5	-	
		4	-	-	
		-	5 ²⁾	-	
Repetitive short circuit current limit $T_j = T_{jt}$ (see timing diagrams) $V_{bb} < 40\text{V}$ $V_{bb} > 40\text{V}$	$I_{L(\text{SCR})}$	-	6	-	
		-	4.5	-	
Output clamp (inductive load switch off) at $V_{\text{OUT}} = V_{bb} - V_{\text{ON}(\text{CL})}$, $I_{bb} = 4\text{mA}$	$V_{\text{ON}(\text{CL})}$	59	63	-	V
Overvoltage protection ³⁾ $I_{bb} = 4\text{mA}$	$V_{bb(\text{AZ})}$	62	-	-	
Thermal overload trip temperature	T_{jt}	150	-	-	$^\circ\text{C}$
Thermal hysteresis	ΔT_{jt}	-	10	-	K

Reverse Battery

Reverse battery ⁴⁾	$-V_{bb}$	-	-	52	V
Drain-source diode voltage ($V_{\text{OUT}} > V_{bb}$) $T_j = 150^\circ\text{C}$	$-V_{\text{ON}}$	-	600	-	mV

¹⁾Integrated protection functions are designed to prevent IC destruction under fault conditions described in the data sheet. Fault conditions are considered as "outside" normal operating range. Protection functions are not designed for continuous repetitive operation.

²⁾not subject to production test, specified by design

³⁾ see also $V_{\text{ON}(\text{CL})}$ in circuit diagram on page 8

⁴⁾Requires a $150\ \Omega$ resistor in GND connection. The reverse load current through the intrinsic drain-source diode has to be limited by the connected load. Power dissipation is higher compared to normal operating conditions due to the voltage drop across the drain-source diode. The temperature protection is not active during reverse current operation! Input current has to be limited (see max. ratings page 3).

Electrical Characteristics

Parameter at $T_j = -40...+150^\circ\text{C}$, $V_{bb} = 12..42\text{V}$, unless otherwise specified	Symbol	Values			Unit
		min.	typ.	max.	
Input and Status feedback					
Input turn-on threshold voltage	$V_{IN(T+)}$	-	-	2.2	V
Input turn-off threshold voltage	$V_{IN(T-)}$	0.8	-	-	
Input threshold hysteresis	$\Delta V_{IN(T)}$	-	0.4	-	
Off state input current $V_{IN} = 0.7\text{ V}$	$I_{IN(off)}$	1	-	25	μA
On state input current $V_{IN} = 5\text{ V}$	$I_{IN(on)}$	3	-	25	
Status output (open drain), Zener limit voltage $I_{ST} = 1.6\text{ mA}$	$V_{ST(high)}$	5.4	6.1	-	V
Status output (open drain), ST low voltage $T_j = -40...+25^\circ\text{C}$, $I_{ST} = 1.6\text{ mA}$ $T_j = 150^\circ\text{C}$, $I_{ST} = 1.6\text{ mA}$	$V_{ST(low)}$	-	-	0.4	
		-	-	0.6	
Status invalid after positive input slope ¹⁾ $V_{bb} = 20\text{ V}$	$t_{d(ST+)}$	-	120	160	μs
Status invalid after negative input slope ¹⁾	$t_{d(ST-)}$	-	250	400	
Input resistance (see page 8)	R_I	2	3.5	5	$\text{k}\Omega$

Diagnostic Characteristics

Short circuit detection voltage	$V_{OUT(SC)}$	-	2.8	-	V
Open load detection voltage ²⁾	$V_{OUT(OL)}$	-	3	4	
Internal output pull down ³⁾ (see page 9 and 14) $V_{OUT(OL)} = 4\text{ V}$	R_O	-	200	-	$\text{k}\Omega$

¹⁾no delay time after overtemperature switch off and short circuit in on-state

²⁾External pull up resistor required for open load detection in off state.

³⁾not subject to production test, specified by design

	Input level	Output level	Status
Normal operation	L	L	H
	H	H	H
Short circuit to GND	L	L	H
	H	L *	L
Short circuit to V_{bb} (in off-state)	L	H	L
	H	H	H
Overload	L	L	H
	H	H **	H
Overtemperature	L	L	H
	H	L	L
Open Load in off-state	L	Z	H (L ¹)
	H	H	H

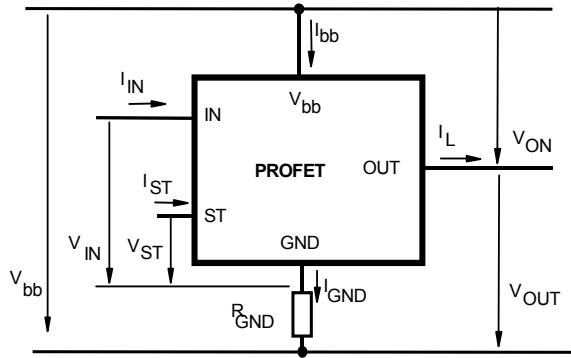
*) Out ="L": $V_{OUT} < 2.8V$ typ.

***) Out ="H": $V_{OUT} > 2.8V$ typ.

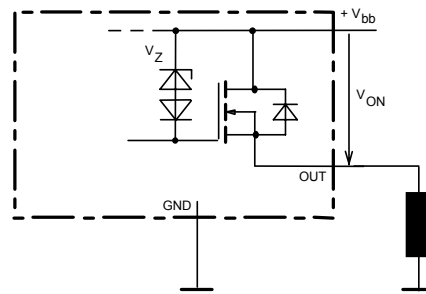
Z = high impedance, potential depends on external circuit

¹with external resistor between V_{bb} and OUT

Terms

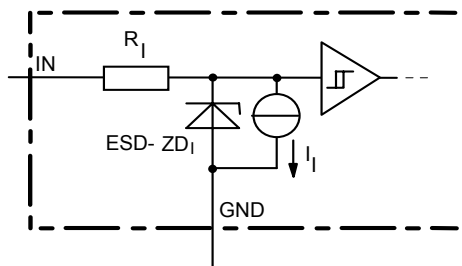


Inductive and overvoltage output clamp



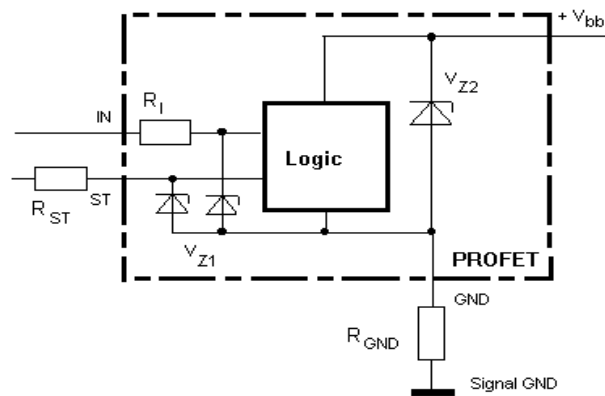
V_{ON} clamped to 59V min.

Input circuit (ESD protection)



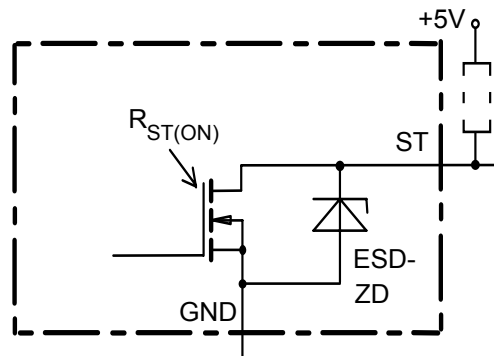
The use of ESD zener diodes as voltage clamp at DC conditions is not recommended

Overvoltage protection of logic part

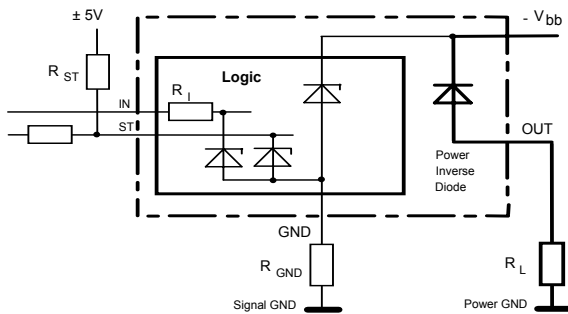


$V_{Z1}=6.1V$ typ., $V_{Z2}=V_{bb(AZ)}=62V$ min.,
 $R_I=3.5\text{ k}\Omega$ typ., $R_{GND}=150\Omega$

Status output



Reverse battery protection

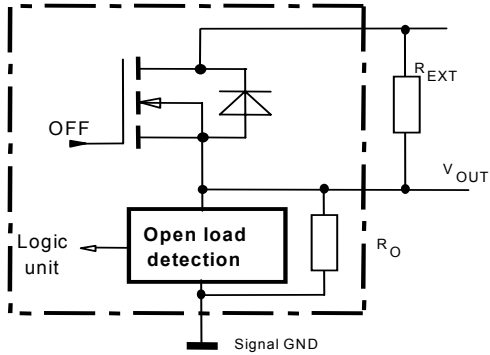


$R_{GND}=150\Omega$, $R_I=3.5\text{ k}\Omega$ typ.,
 Temperature protection is not active during inverse current

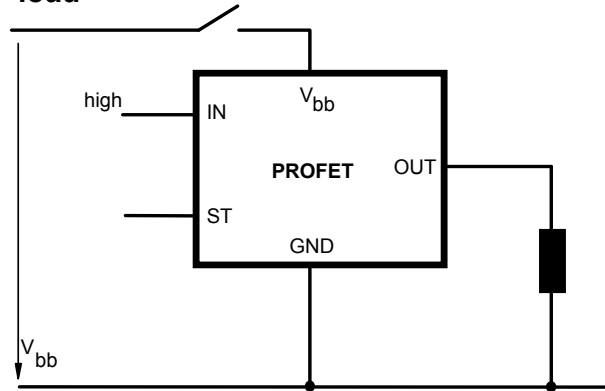
Open-load detection

OFF-state diagnostic condition:

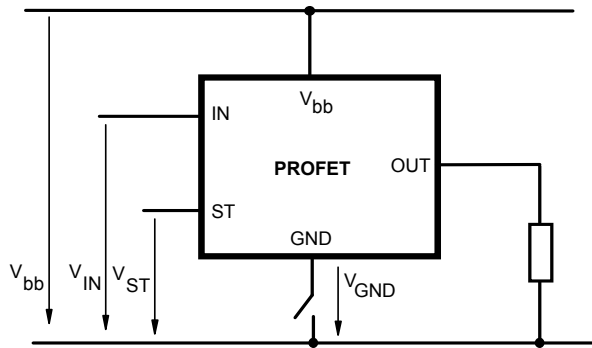
$V_{OUT} > 3V$ typ.; $I_N = \text{low}$



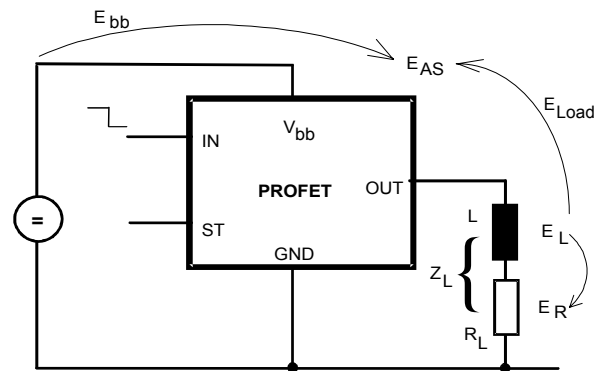
V_{bb} disconnect with charged inductive load



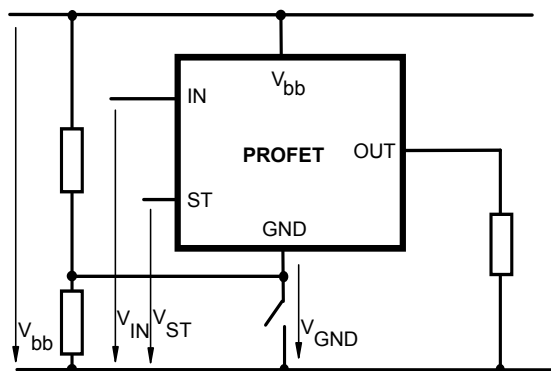
GND disconnect



Inductive Load switch-off energy dissipation



GND disconnect with GND pull up



Energy stored in load inductance: $E_L = \frac{1}{2} * L * I_L^2$

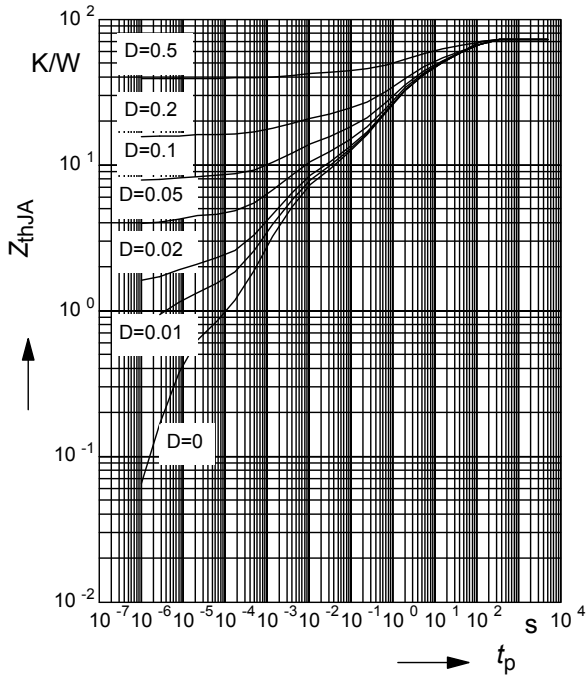
While demagnetizing load inductance, the energy dissipated in PROFET is $E_{AS} = E_{bb} + E_L - E_R = V_{ON(CL)} * i_L(t) dt$, with an approximate solution for $R_L > 0\Omega$:

$$E_{AS} = \frac{I_L * L}{2 * R_L} * (V_{bb} + |V_{OUT(CL)}|) * \ln\left(1 + \frac{I_L * R_L}{|V_{OUT(CL)}|}\right)$$

Typ. transient thermal impedance

$Z_{thJA} = f(t_p)$ @ 6cm² heatsink area

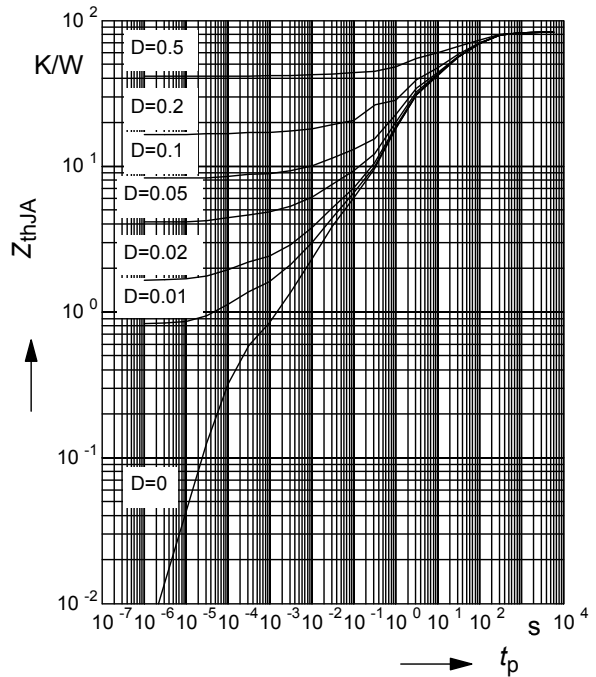
Parameter: $D = t_p / T$



Typ. transient thermal impedance

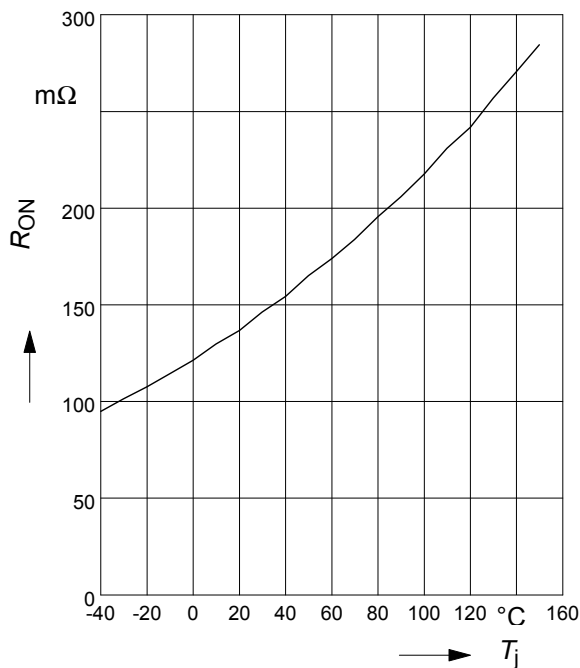
$Z_{thJA} = f(t_p)$ @ min. footprint

Parameter: $D = t_p / T$



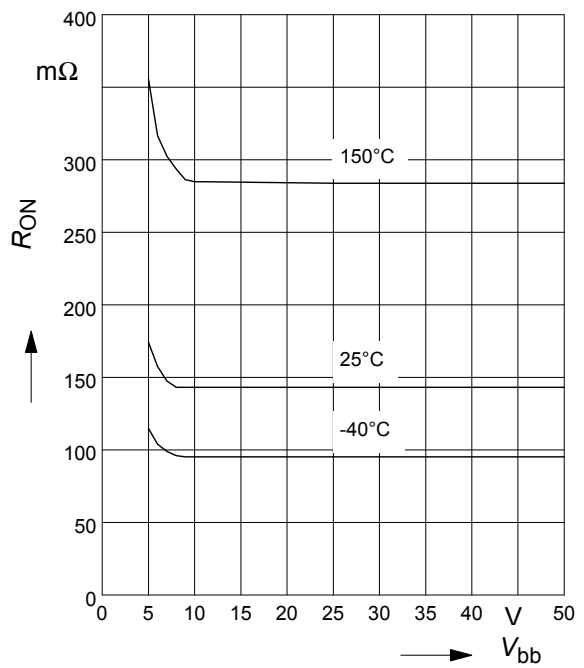
Typ. on-state resistance

$R_{ON} = f(T_j)$; $V_{bb} = 13,5V$; $V_{in} = high$



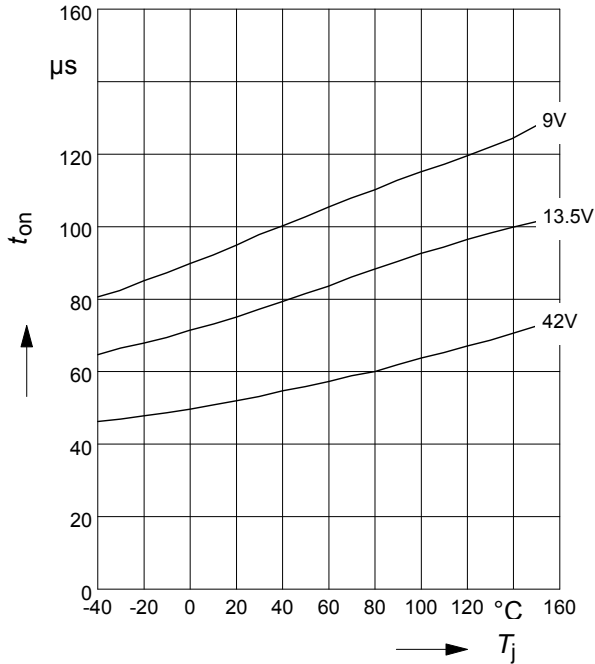
Typ. on-state resistance

$R_{ON} = f(V_{bb})$; $I_L = 1 A$; $V_{in} = high$



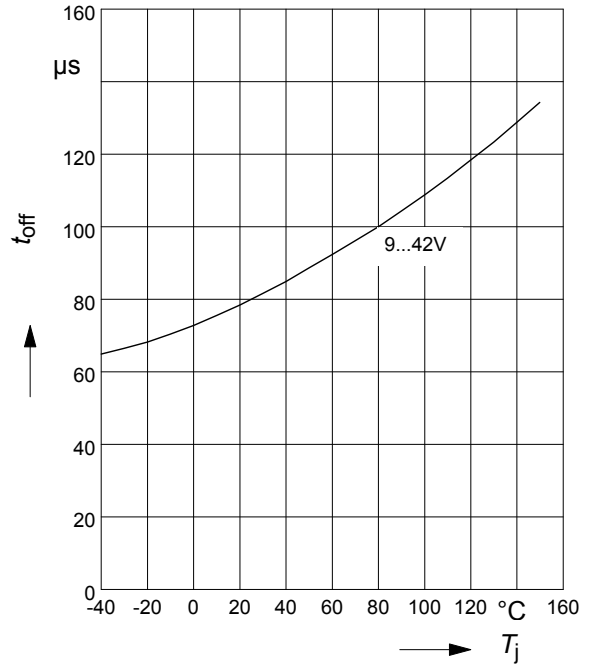
Typ. turn on time

$t_{on} = f(T_j); R_L = 47\Omega$



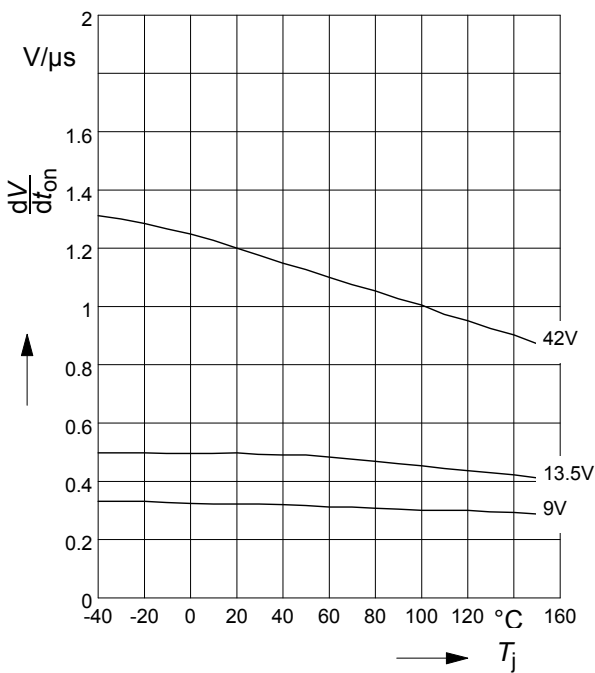
Typ. turn off time

$t_{off} = f(T_j); R_L = 47\Omega$



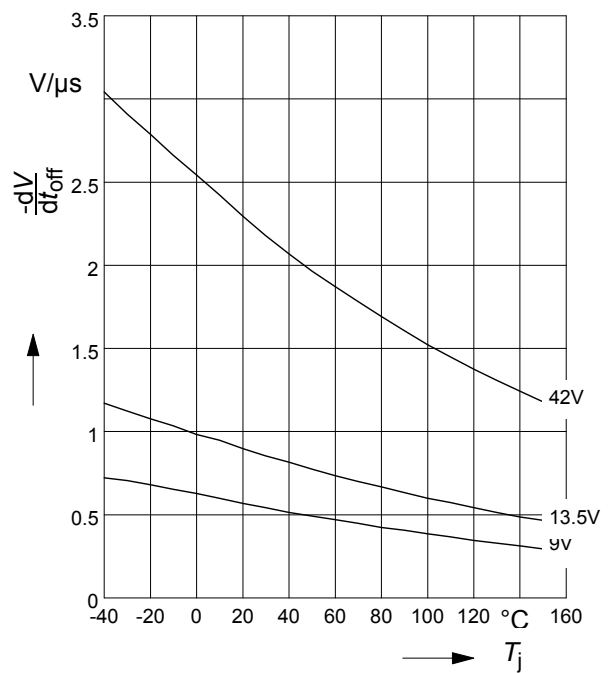
Typ. slew rate on

$dV/dt_{on} = f(T_j); R_L = 47\Omega$



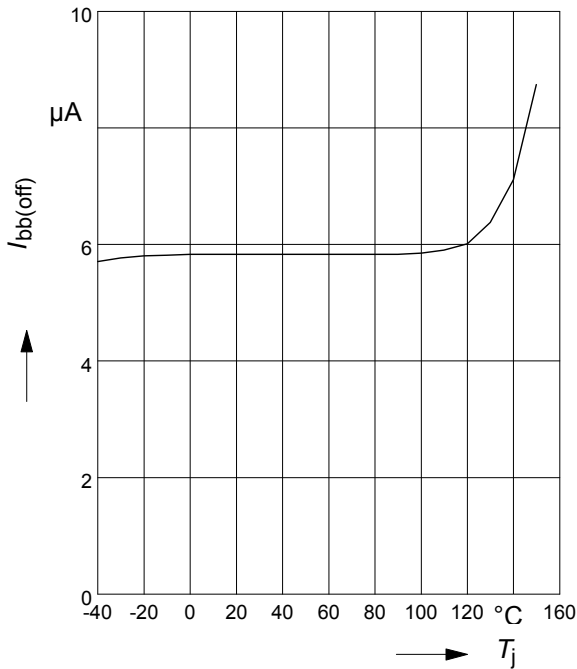
Typ. slew rate off

$dV/dt_{off} = f(T_j); R_L = 47\Omega$



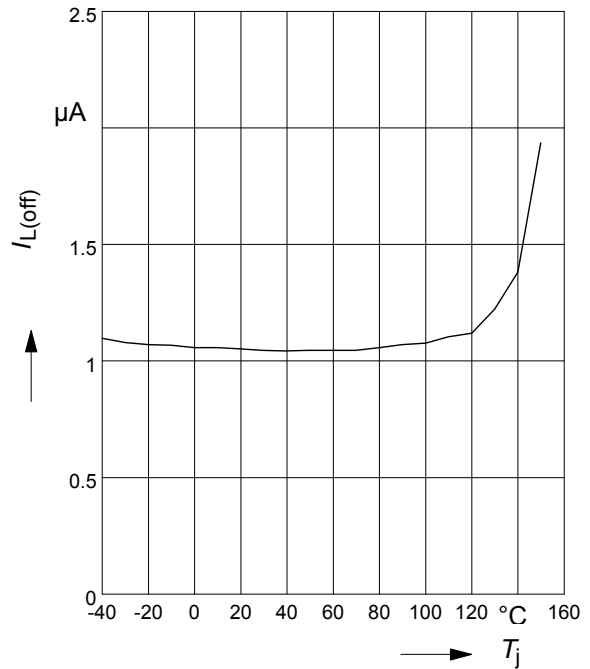
Typ. standby current

$I_{bb(off)} = f(T_j) ; V_{bb} = 42V ; V_{IN} = low$



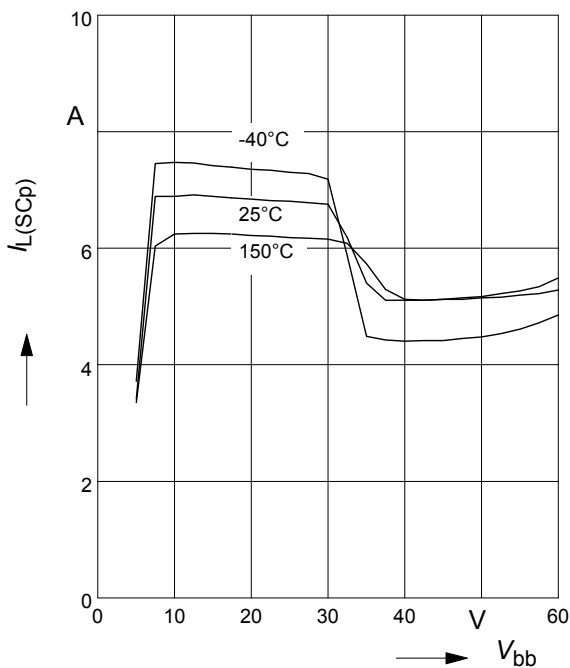
Typ. leakage current

$I_{L(off)} = f(T_j) ; V_{bb} = 42V ; V_{IN} = low$



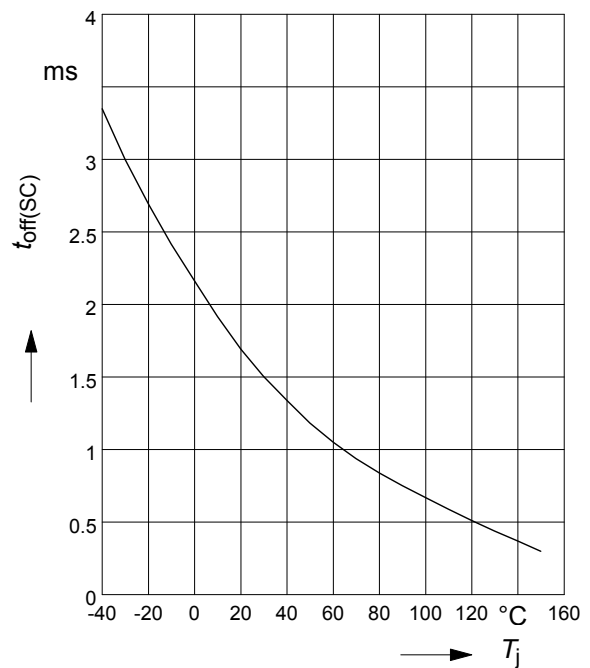
Typ. initial peak short circuit current limit

$I_{L(SCp)} = f(V_{bb})$



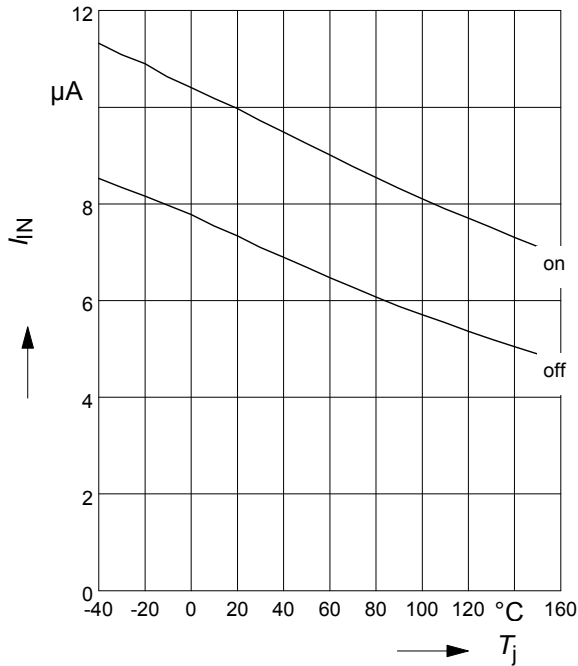
Typ. initial short circuit shutdown time

$t_{off(SC)} = f(T_{j,start}) ; V_{bb} = 20V$



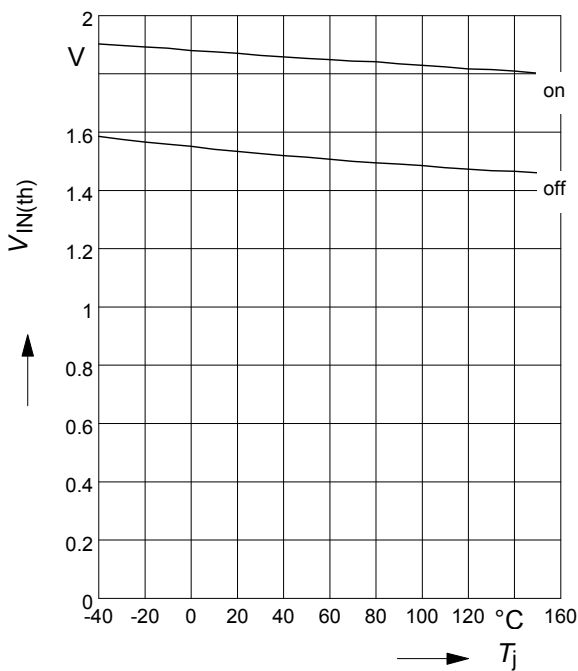
Typ. input current

$I_{IN(on/off)} = f(T_j)$; $V_{bb} = 13,5V$; $V_{IN} = \text{low/high}$
 $V_{INlow} \leq 0,7V$; $V_{INhigh} = 5V$



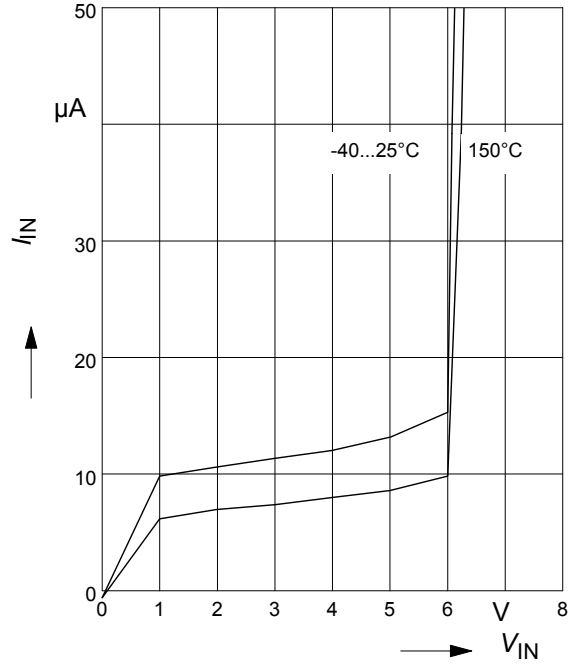
Typ. input threshold voltage

$V_{IN(th)} = f(T_j)$; $V_{bb} = 13,5V$



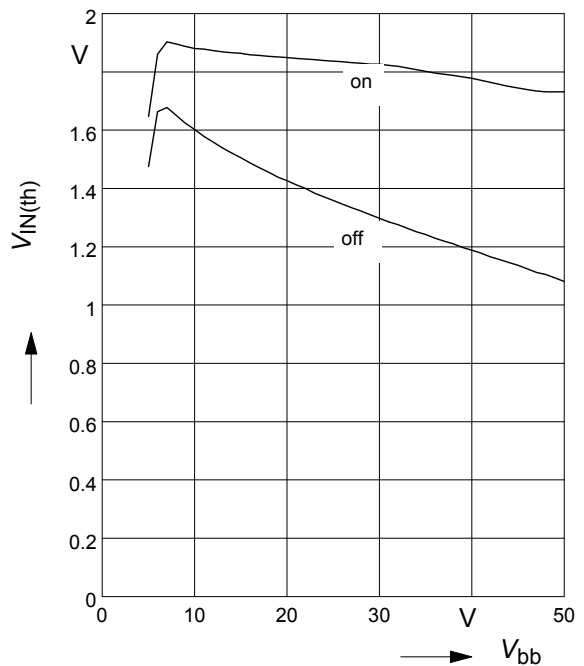
Typ. input current

$I_{IN} = f(V_{IN})$; $V_{bb} = 13.5V$



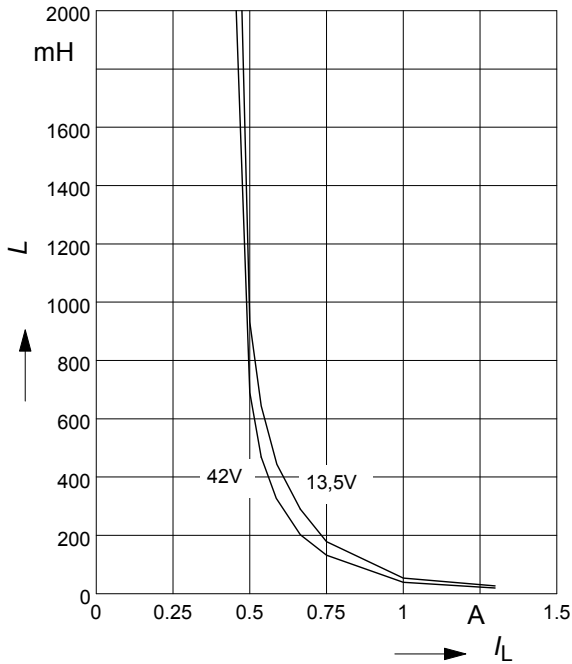
Typ. input threshold voltage

$V_{IN(th)} = f(V_{bb})$; $T_j = 25^{\circ}C$



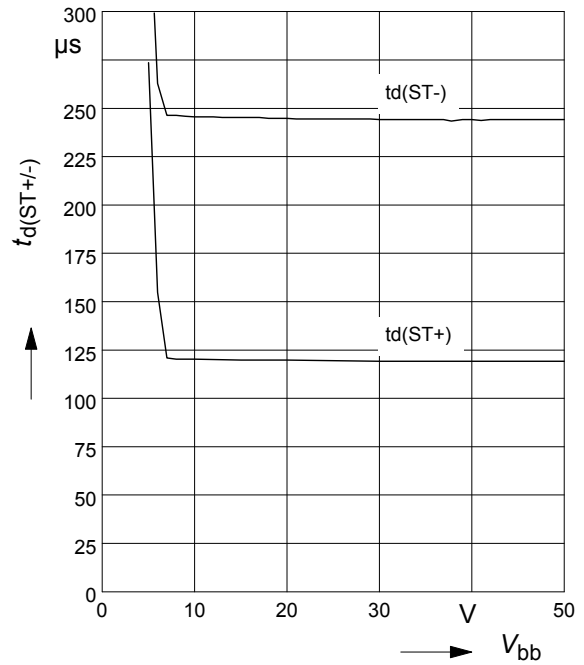
Maximum allowable load inductance for a single switch off

$L = f(I_L); T_{jstart}=150^{\circ}C, R_L=0\Omega$



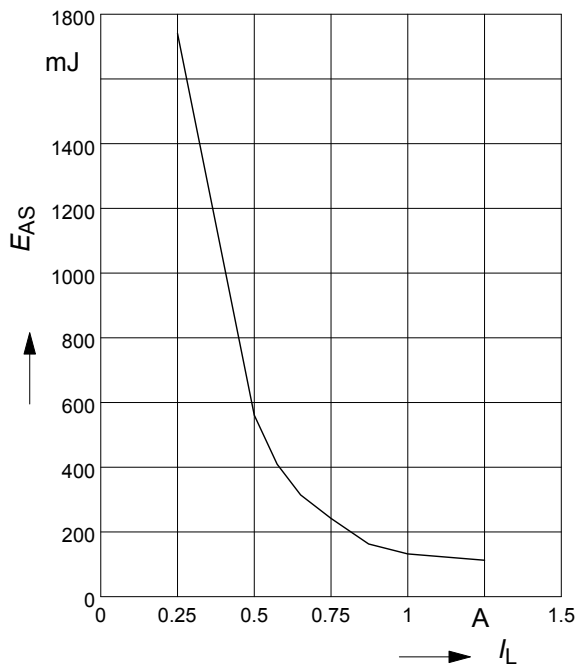
Typ. status delay time

$t_{d(ST)} = f(V_{bb}); T_j = 25^{\circ}C$



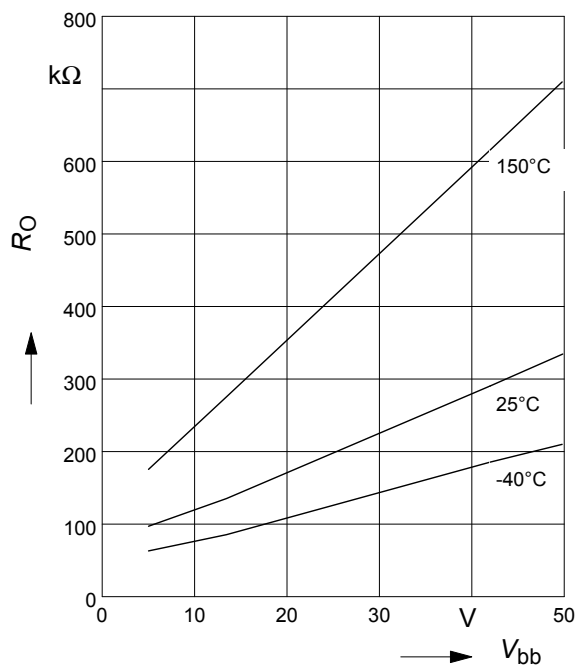
Maximum allowable inductive switch-off energy, single pulse

$E_{AS} = f(I_L); T_{jstart} = 150^{\circ}C, V_{bb} = 13.5V$



Typ. internal output pull down

$R_O = f(V_{bb})$



Timing diagrams

Figure 1a: V_{bb} turn on:

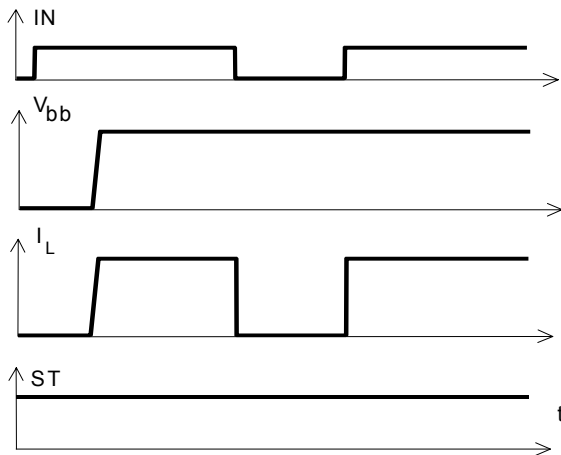


Figure 2b: Switching a lamp,

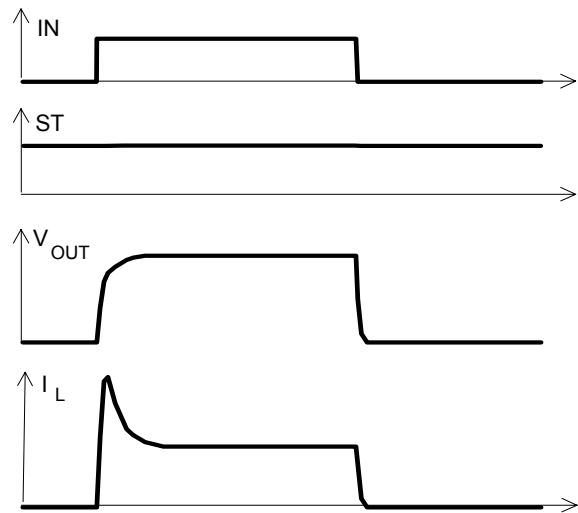


Figure 2a: Switching a resistive load, turn-on/off time and slew rate definition

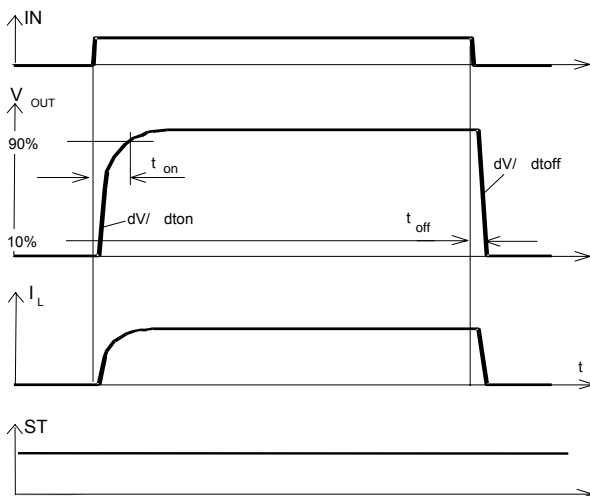


Figure 2c: Switching an inductive load

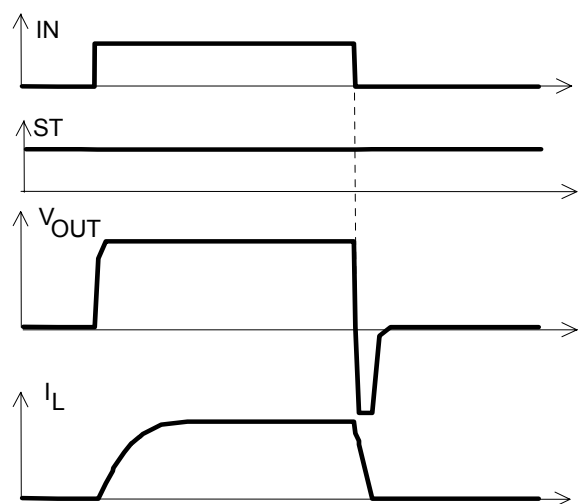
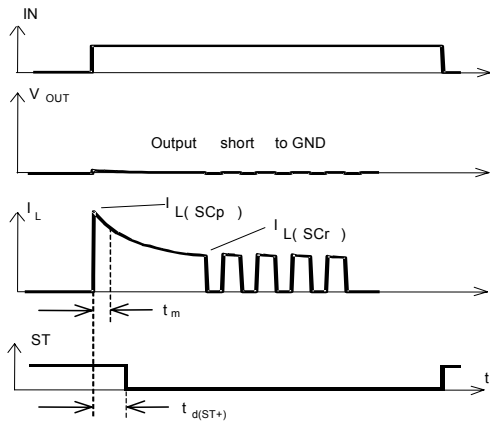


Figure 3a: Turn on into short circuit, shut down by overtemperature, restart by cooling



Heating up of the chip may require several milliseconds, depending on external conditions.

Figure 4: Overtemperature: Reset if $T_j < T_{jt}$

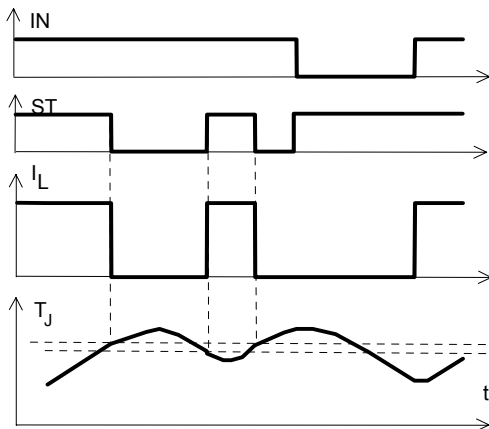


Figure 3b: Short circuit in on-state shut down by overtemperature, restart by cooling

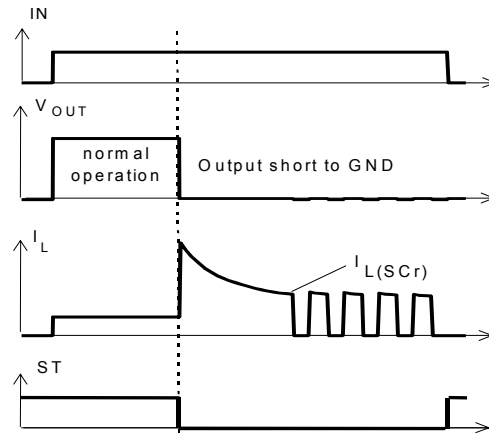
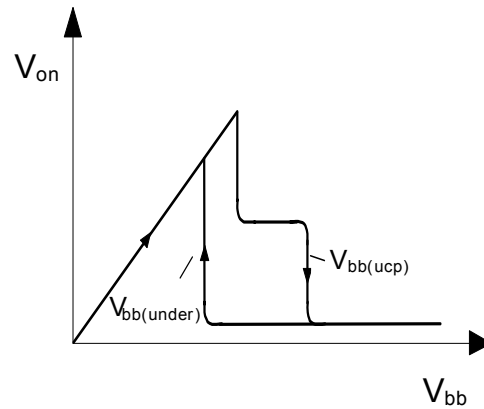


Figure 5: Undervoltage restart of charge pump

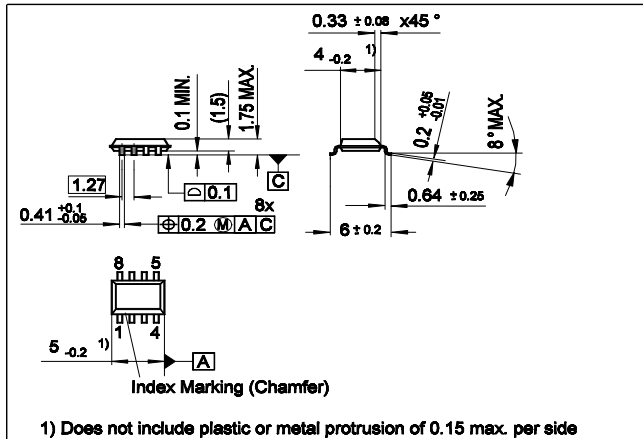


Package and ordering code

all dimensions in mm

Package: Ordering code:

PG-DSO-8	SP000219825
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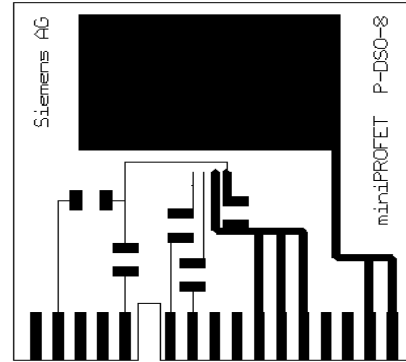
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For further information on technology, delivery terms and conditions and prices please contact your nearest Infineon Technologies Office in Germany or our Infineon Technologies Representatives worldwide (see address list).

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Printed circuit board (FR4, 1.5mm thick, one layer 70µm, 6cm² active heatsink area) as a reference for max. power dissipation P_{tot} nominal load current $I_{L(nom)}$ and thermal resistance R_{thja}